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FPF1048 IntelliMAX[™] 3 A-Capable, Slew-Rate-Controlled Load Switch with True Reverse Current Blocking

Features

- Input Voltage Operating Range: 1.5 V to 5.5 V
- Typical R_{DS(ON)}:
 - 21 mΩ at V_{IN}=5.5 V
 - 23 mΩ at V_{IN}=4.5 V
 - 41 m Ω at V_{IN}=1.8 V
 - 90 m Ω at V_{IN}=1.5 V
- Slew Rate/Inrush Control with t_R: 2.7 ms (Typ.)
- 3 A Maximum Continuous Current Capability
- Low Off Switch Current: <1 µA</p>
- True Reverse Current Blocking (TRCB)
- Logic CMOS IO Meets JESD76 Standard for GPIO Interface and Related Power Supply Requirements
- ESD Protected:
 - Human Body Model: >8 kV
 - Charged Device Model: >1.5 kV
 - IEC 61000-4-2 Air Discharge: >15 kV
 - IEC 61000-4-2 Contact Discharge: >8 kV

Applications

- Smart Phones, Tablet PCs
- Storage, DSLR, and Portable Devices

Description

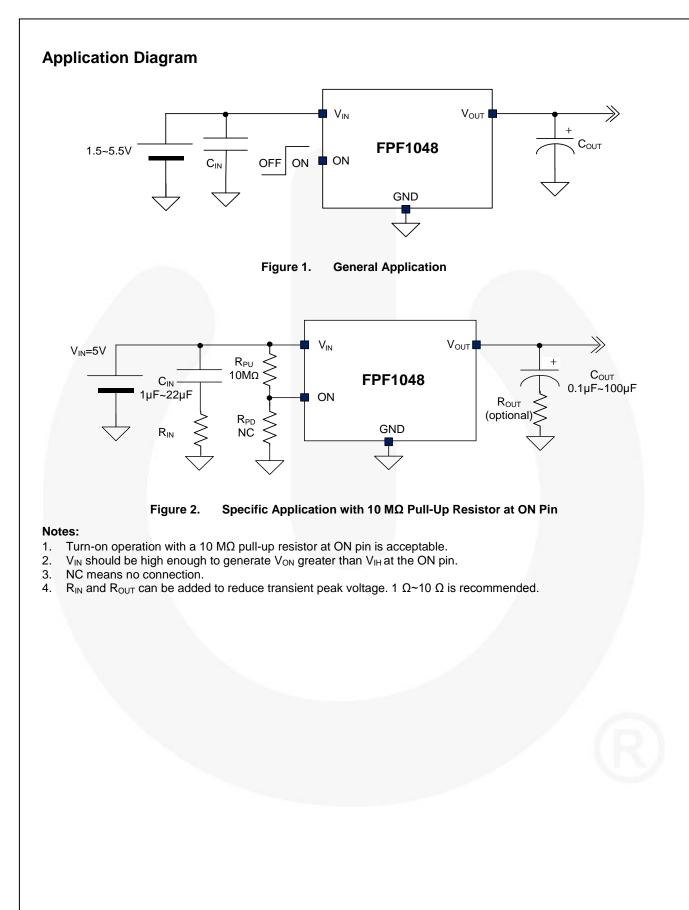
The FPF1048 advanced load management switch targets applications requiring a highly integrated solution. It disconnects loads powered from the DC power rail (<6 V) with stringent off-state current targets and high load capacitances (up to $100 \ \mu$ F). The FPF1048 consists of slew-rate controlled low-impedance MOSFET switch (23 m Ω typical) and integrated analog features. The slew-rate controlled turn-on characteristic prevents inrush current and the resulting excessive voltage droop on power rails.

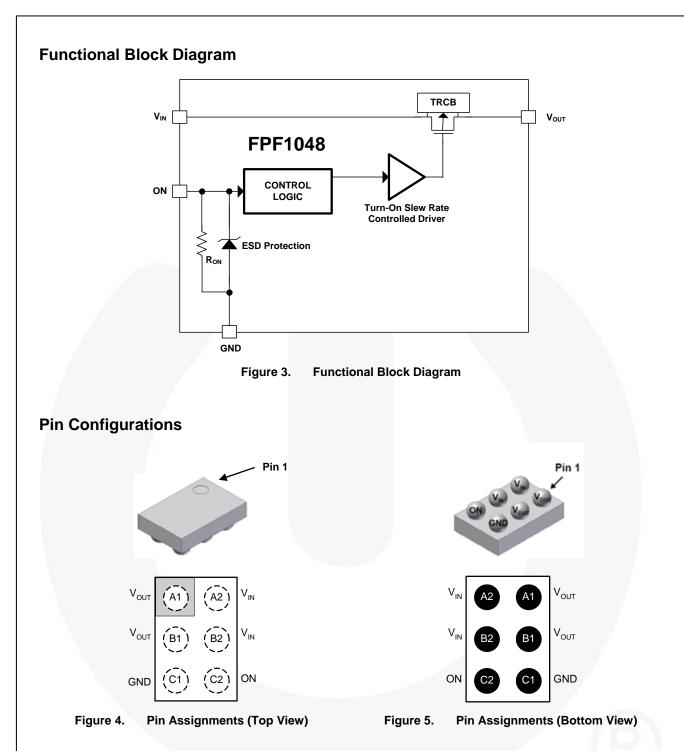
The FPF1048 has a True Reverse Current Blocking (TRCB) function that obstructs unwanted reverse current from V_{OUT} to V_{IN} during both ON and OFF states. The exceptionally low off-state current drain (<1µA maximum) facilitates compliance with standby power requirements. The input voltage range operates from 1.5 V to 5.5 V_{DC} to support a wide range of applications in consumer, optical, medical, storage, portable, and industrial-device power management. Switch control is managed by a logic input (active HIGH) capable of interfacing directly with low-voltage control signal / General-Purpose Input / Output (GPIO) without an external pull-down resistor.

The device is packaged in advanced, fully "green" compliant, 1.0 mm x 1.5 mm, Wafer-Level Chip-Scale Package (WLCSP) with backside lamination.

Part Number	Top Mark	Switch R _{on} (Typical) at 4.5V _{IN}	Input Buffer	Output Discharge	ON Pin Activity	t _R	Package	
FPF1048BUCX	RA	23 mΩ	CMOS	NA	Active HIGH	2.7 ms	6-Ball, WLCSP with Backside Laminate, 2x3 Array, 0.5 mm Pitch, 300 μm Balls	

Ordering Information





Pin Description

Pin #	Name	Description			
A1, B1	V _{OUT}	itch Output			
A2, B2	V _{IN}	upply Input: Input to the Power Switch			
C1	GND	round			
C2	ON	ON/OFF Control, Active High, GPIO Compatible			

FPF1048-— IntelliMAX ™ 3A-Capable, Slew-Rate-Controlled Load Switch with True Reverse Blocking

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameters			Min.	Max.	Unit
V _{IN}	V _{IN} , V _{OUT} , V _{ON} to GND			-0.3	6.0	V
I _{SW}	Maximum Continuous Switch Current				3.0	A
PD	Power Dissip	Power Dissipation at T _A =25°C			1.2	W
T _{STG}	Storage Junction Temperature			-65	+150	°C
T _A	Operating Te	Operating Temperature Range			+85	°C
Q	Thermal Resistance, Junction-to-Ambient				85 ⁽⁵⁾	°C/W
Θ_{JA}					110 ⁽⁶⁾	0/11
		Human Body M	Iodel, JESD22-A114	8.0		
ESD	Electrostatic Discharge Capability	Charged Device Model, JESD22-C101				kV
		.	Air Discharge (VIN, VON, VOUT to GND)	15.0		κν
		System Level	Contact Discharge (VIN, VON, VOUT to GND)	8.0		

Notes:

- 5. Measured using 2S2P JEDEC std. PCB.
- 6. Measured using 2S2P JEDEC PCB cold plate method.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameters	Min.	Тур.	Max.	Unit
VIN	Input Voltage	1.5		5.5	V
T _A	Ambient Operating Temperature			+85	°C
Isw	Continuous Switch Current		2.5	3	А

Symbol	Parameters	Conditions	Min.	Тур.	Max.	Units		
Basic Op	peration		•		•			
VIN	Input Voltage		1.5		5.5	V		
I _{Q(OFF)}	Off Supply Current	V _{ON} =GND, V _{OUT} =Open			1	μA		
I _{SD}	Shutdown Current	V_{ON} =GND, V_{OUT} =GND, T_A = -40 to +85°C		0.2	4.0	μA		
lq	Quiescent Current	I _{OUT} =0 mA			11	μA		
		V _{IN} =5.5 V, I _{OUT} =3 A ⁽⁷⁾		22.0				
		V_{IN} =5.5 V, I_{OUT} =2 $A^{(7)}$		21.5				
		V_{IN} =5.5 V, I_{OUT} =1 A, T_A =25°C		21.0	28.0			
		V _{IN} =4.5 V, I _{OUT} =3 A ⁽⁷⁾		24.0				
R _{ON}	On Resistance	V _{IN} =4.5 V, I _{OUT} =2 A ⁽⁷⁾		23.5		m0		
RON	On Resistance	V _{IN} =4.5 V, I _{OUT} =1 A, T _A =25°C		23.0	30.0	mΩ		
		V _{IN} =3.3 V, I _{OUT} =500 mA, T _A =25°C		26.0		1		
		V _{IN} =2.5 V, I _{OUT} =500 mA, T _A =25°C		30.0				
		V _{IN} =1.8 V, I _{OUT} =250 mA, T _A =25°C		41.0				
		V_{IN} =1.5 V, I_{OUT} =250 mA, T_A =25°C		90.0	110.0			
VIH	ON Input Logic High Voltage	$V_{\text{IN}}\text{=}1.5$ V to 5.5 V	1.15			V		
VIL	ON Input Logic Low Voltage	V _{IN} =1.8 V to 5.5 V			0.65	V		
VIL	ON Input Logic Low Voltage	V_{IN} =1.5 V to 1.8 V			0.60	V		
I _{ON}	ON Input Leakage	V _{ON} = V _{IN} or GND			1.0	μA		
R_{ON_PD}	Pull-Down Resistance at ON Pin	$V_{\text{IN}}\text{=}~V_{\text{ON}}$ = 1.5 V to 5.5 V, $T_{\text{A}}\text{=}$ -40 - +85°C	6.38	7.65	8.86	MΩ		
True Rev	erse Current Blocking							
V_{T_RCB}	RCB Protection Trip Point	Vout - Vin		45		mV		
V _{R_RCB}	RCB Protection Release Trip Point	V _{IN} -V _{OUT}		25		mV		
	RCB Hysteresis		6	70		mV		
I _{SD_OUT}	V _{OUT} Shutdown Current	$V_{ON} = 0$, $V_{OUT} = 4.5$ V, $V_{IN} =$ Short to GND			2	μA		
t _{RCB_ON}	RCB Response Time, Device ON	V _{OUT} - V _{IN} =100 mV, V _{ON} = HIGH		4		μs		
t _{RCB_OFF}	RCB Response Time, Device OFF	V _{OUT} - V _{IN} =100 mV, V _{ON} = LOW		2.5		μs		
Dynamic	Characteristics							
t _{DON}	Turn-On Delay ^(8,9)			1.7		ms		
t _R	V _{OUT} Rise Time ^(8,9)	V_{IN} =4.5 V, R _L =5 Ω , C _L =100 µF, T _A =25°C		2.7		ms		
t _{ON}	Turn-On Time ^(8,9)		/	4.4		ms		
t _{DON}	Turn-On Delay ^(8,9)	V _{IN} =4.5 V, R _L =150 Ω, C _L =100 μF, T _A =25°C		1.7		ms		
t _R	V _{OUT} Rise Time ^(8,9)			1.5		ms		
t _{ON}	Turn-On Time ^(8,9)			3.2		ms		
t _{DOFF}	Turn-Off Delay ^(8,10)			1.8		ms		
t⊧	V _{OUT} Fall Time ^(8,10)	V _{IN} =4.5 V, R _L =150 Ω, C _L =100 μF, T _A =25°C		34		ms		
t _{OFF}	Turn-Off Time ^(8,10)			35		ms		

Notes:

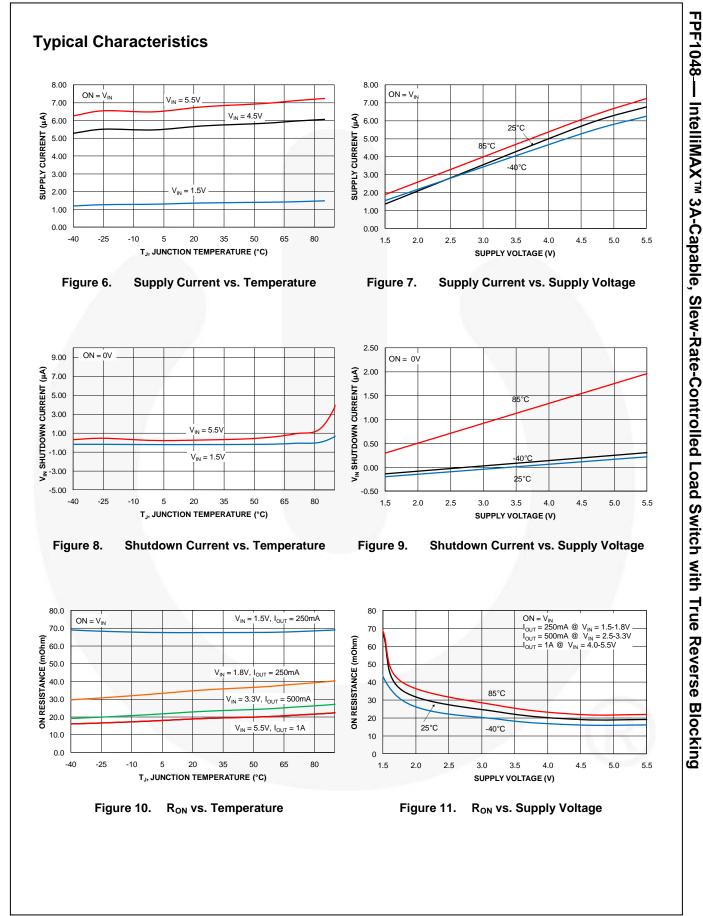
7. This parameter is guaranteed by design and characterization; not production tested.

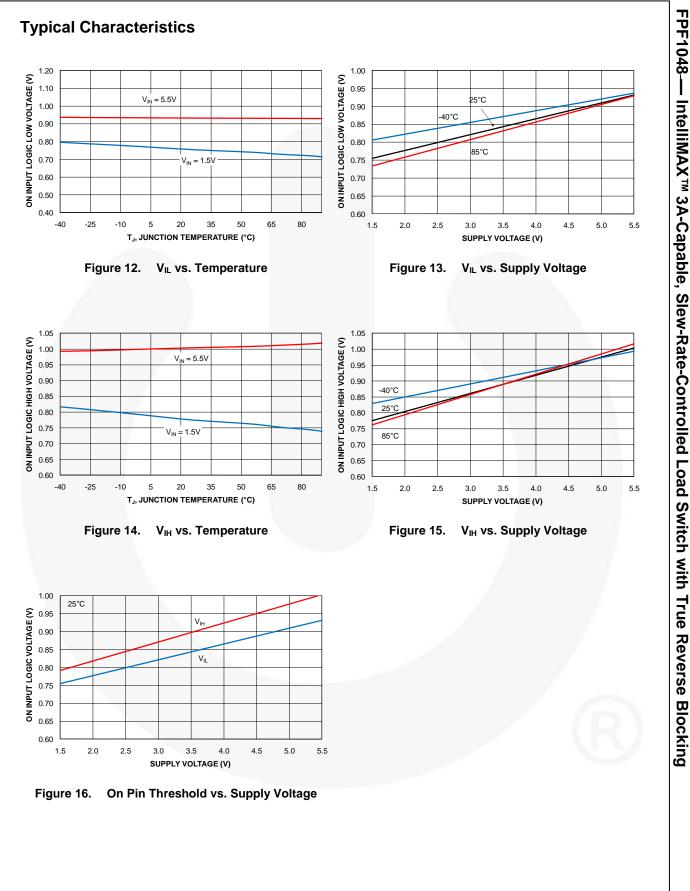
8. $t_{DON}/t_{DOFF}/t_R/t_F$ are defined in Figure 22.

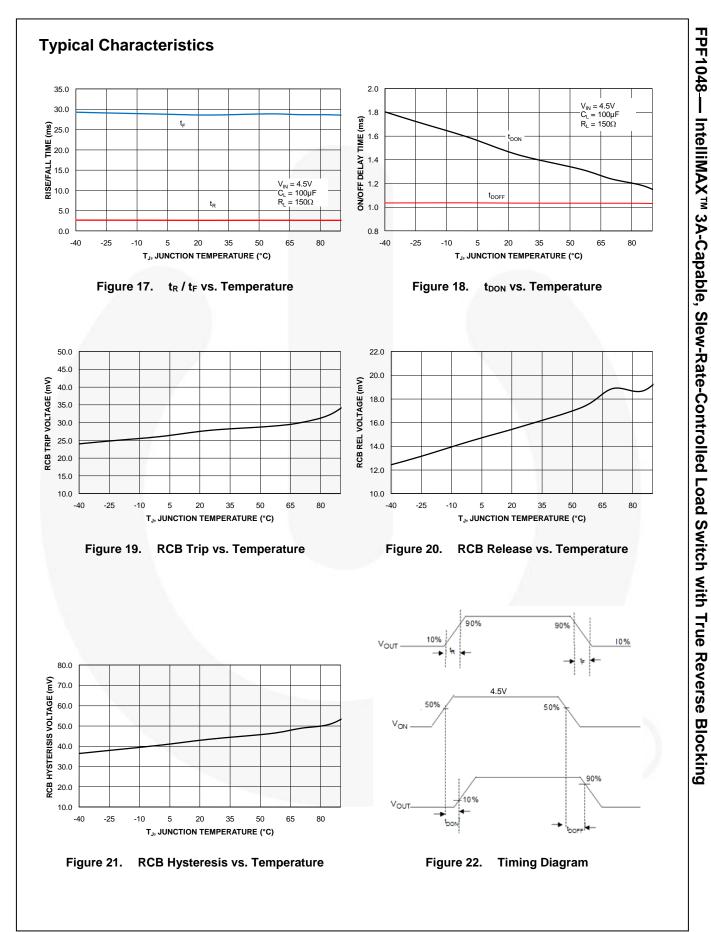
Electrical Characteristics

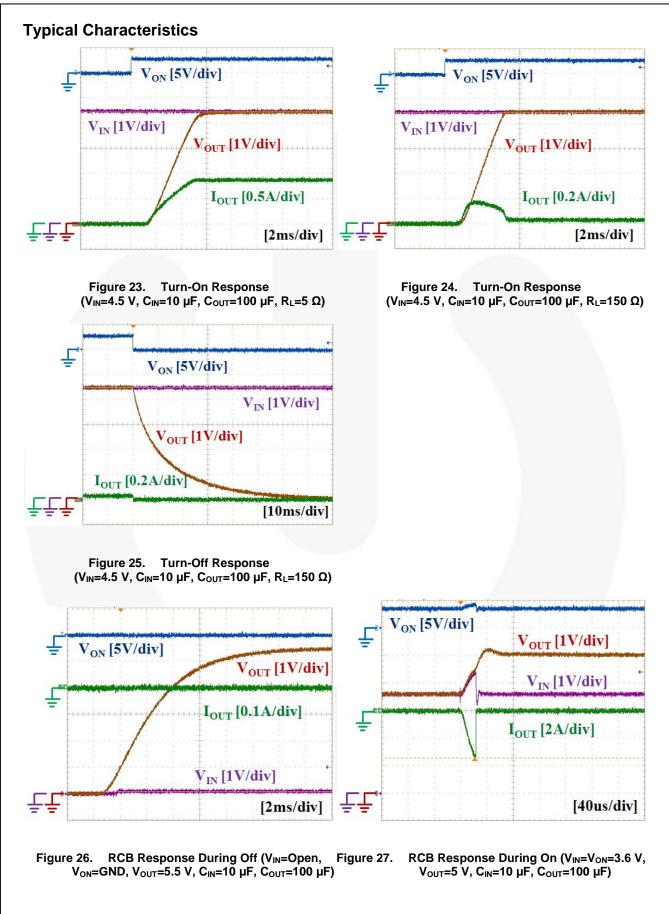
9. $t_{ON}=t_R + t_{DON}$.

10. t_{OFF}=t_F + t_{DOFF}.









Operation and Application Description

The FPF1048 is a low-R_{ON} P-channel load switch with controlled turn-on and True Reverse Current Blocking (TRCB). The core is a 23 m Ω P-channel MOSFET and controller capable of functioning over a wide input operating range of 1.5 to 5.5 V. The ON pin, an active-HIGH, GPIO/CMOS-compatible input; controls the state of the switch. TRCB functionality blocks unwanted reverse current during both ON and OFF states when higher V_{OUT} than V_{IN} is applied.

Input Capacitor

To limit the voltage drop on the input supply caused by transient inrush current when the switch turns on into a discharged load capacitor; a capacitor must be placed between the V_{IN} and GND pins. At least 1 μ F ceramic capacitor, C_{IN}, placed close to the pins is usually sufficient. Higher-value C_{IN} can be used to reduce the voltage drop in higher-current applications.

Inrush Current

Inrush current occurs when the device is turned on. Inrush current is dependent on output capacitance and slew rate control capability, as expressed by:

$$I_{INRUSH} = C_{OUT} \times \frac{V_{IN} - V_{INITIAL}}{t_R} + I_{LOAD}$$
(1)

where:

- COUT: Output capacitance;
- t_R: Slew rate or rise time at V_{OUT};
- V_{IN}: Input voltage;
- VINITIAL: Initial voltage at COUT, usually GND; and
- ILOAD: Load current.

Higher inrush current causes higher input voltage drop, depending on the distributed input resistance and input capacitance. High inrush current can cause problems.

FPF1048 has a 2.7 ms of slew rate capability under 4.5 V_{IN} at 1000 μ F of C_{OUT} and 5 Ω of R_L so inrush current can be minimized and no input voltage drop appears. Table 1 and Figure 28 show the values and actual waveforms with C_{IN}=10 μ F, C_{OUT}=100 μ F, and no load current.

Table 1. Inrush Current by Input Voltage

		Inrush Current [mA]			
V _{IN} [V]	t _R [ms]	Measured	Calculated with 2.7 ms t_R		
1.5	1.62	76	56		
3.3	2.03	140	122		
5.0	2.33	196	185		

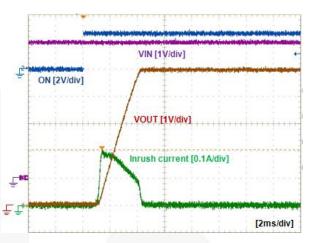


Figure 28. Inrush Current Waveform, Under 5 V_{IN} , C_{OUT}=100 μ F, no Load

Output Capacitor

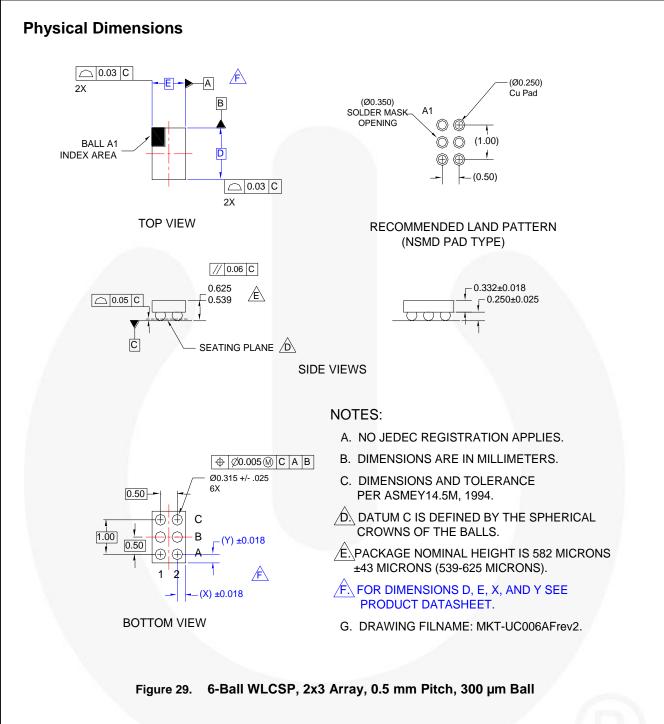
At least 0.1 μ F capacitor, C_{OUT}, should be placed between the V_{OUT} and GND pins. This capacitor prevents parasitic board inductance from forcing V_{OUT} below GND when the switch is on.

True Reverse Current Blocking

The true reverse current blocking feature protects the input source against current flow from output to input regardless of whether the load switch is on or off.

Board Layout

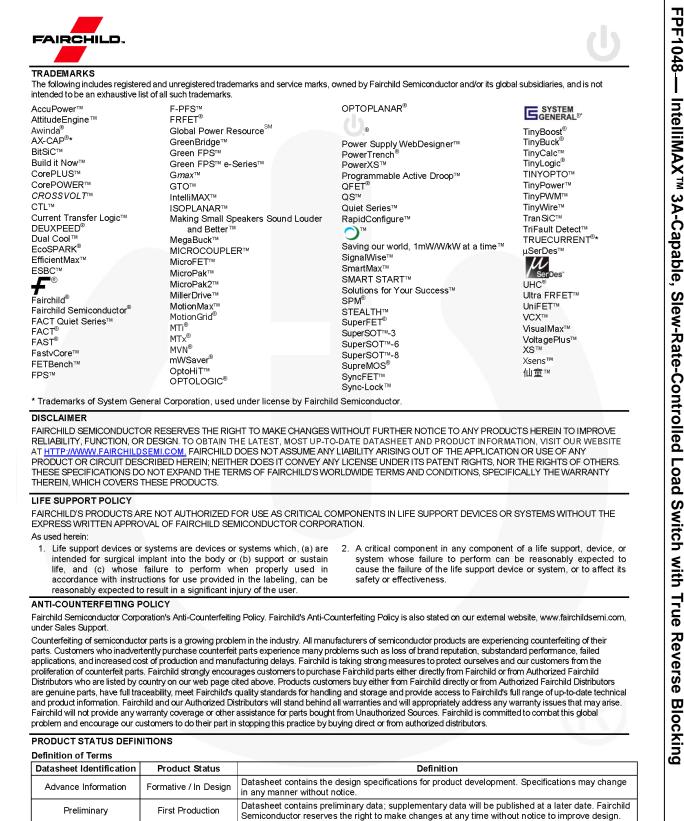
For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effect that parasitic trace inductance on normal and short-circuit operation. Using wide traces or large copper planes for all pins (V_{IN} , V_{OUT} , ON, and GND) minimizes the parasitic electrical effects and the case-to-ambient thermal impedance.



Product-Specific Dimensions

Product	D	E	X	Y
FPF1048BUCX	1460 μm ±30 μm	960 μm ±30 μm	230 µm	230 µm

FPF1048-— IntelliMAX ™ 3A-Capable, Slew-Rate-Controlled Load Switch with True Reverse Blocking



No Identification Needed

Obsolete

Full Production

Not In Production

Rev. 174

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